

TaS₂ nanosheets-based ultrafast response and flexible humidity sensor for multifunctional applications

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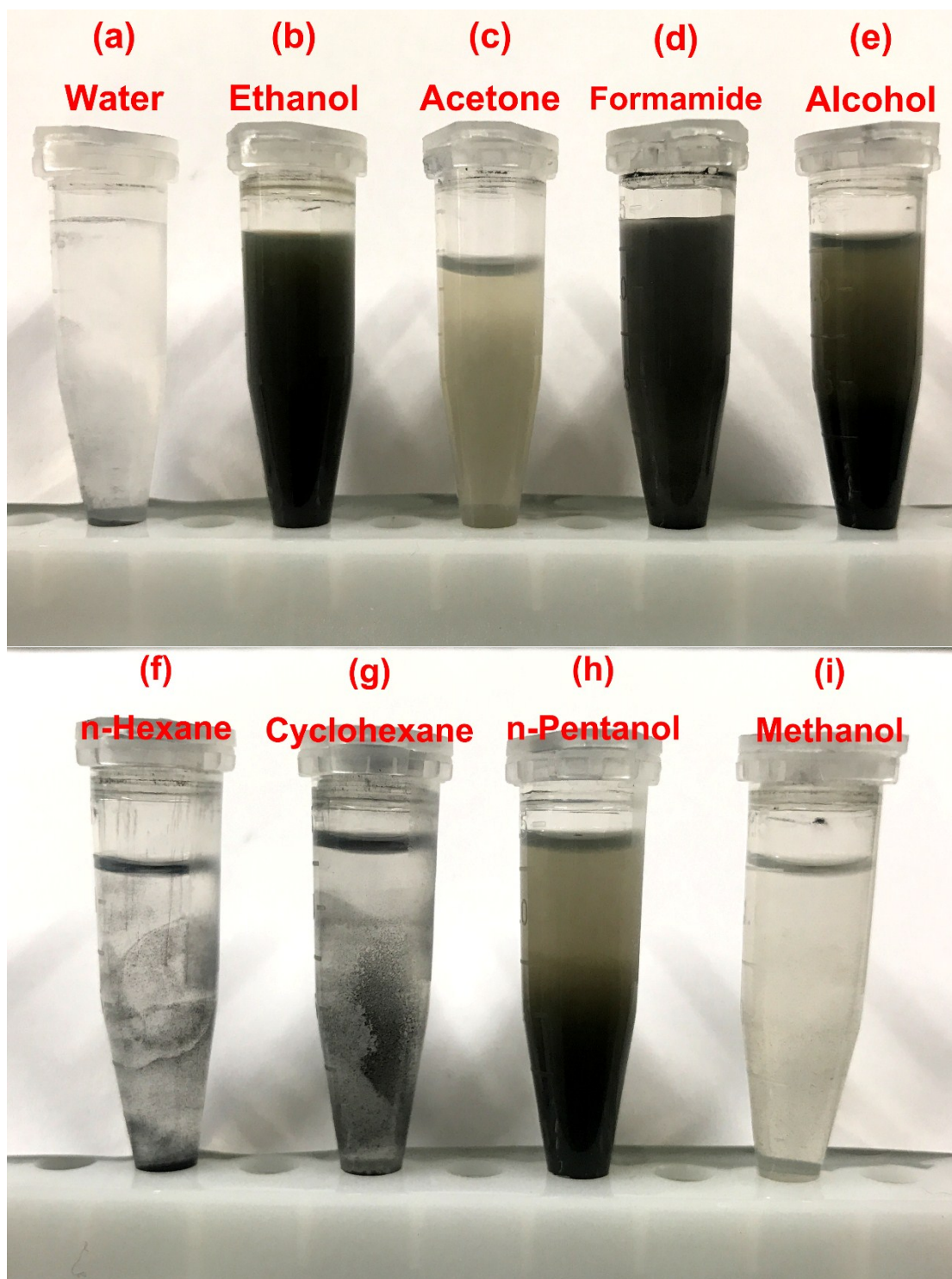


Figure S1. Comparison of the exfoliation efficiency between various solvents.

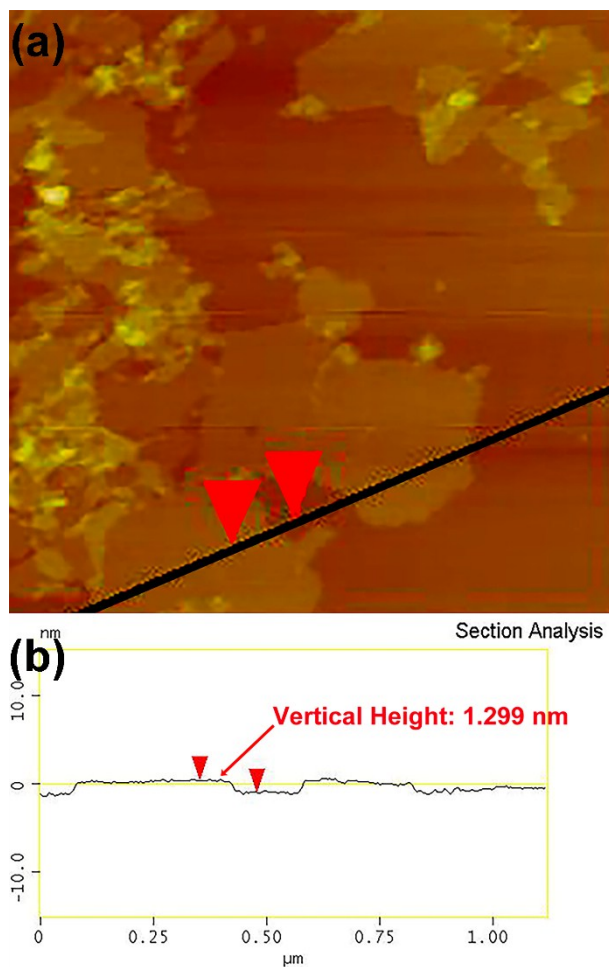


Figure S2. (a) AFM image of TaS₂ nanosheets. (b) The height profile along the marked line in part (a).

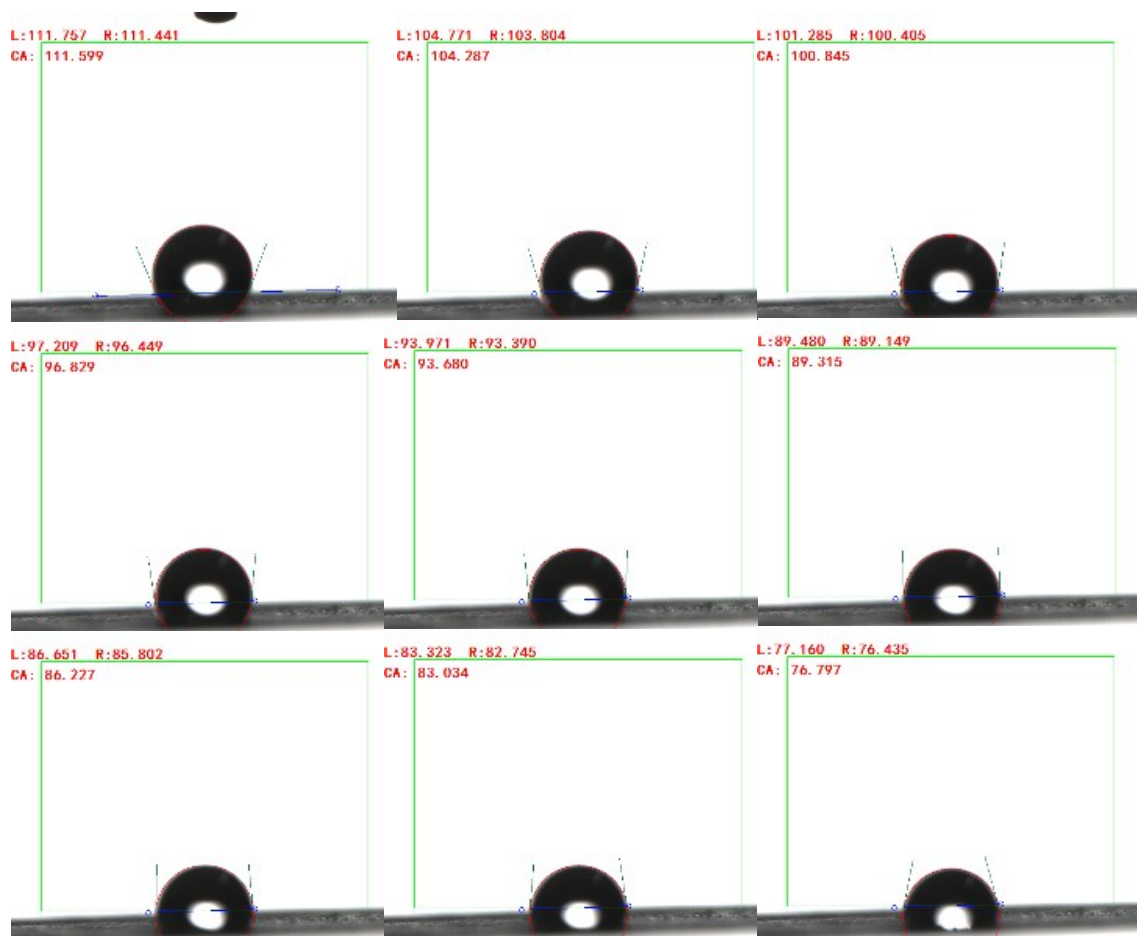


Figure S3. The change process of the contact angle of PET interdigital electrode.

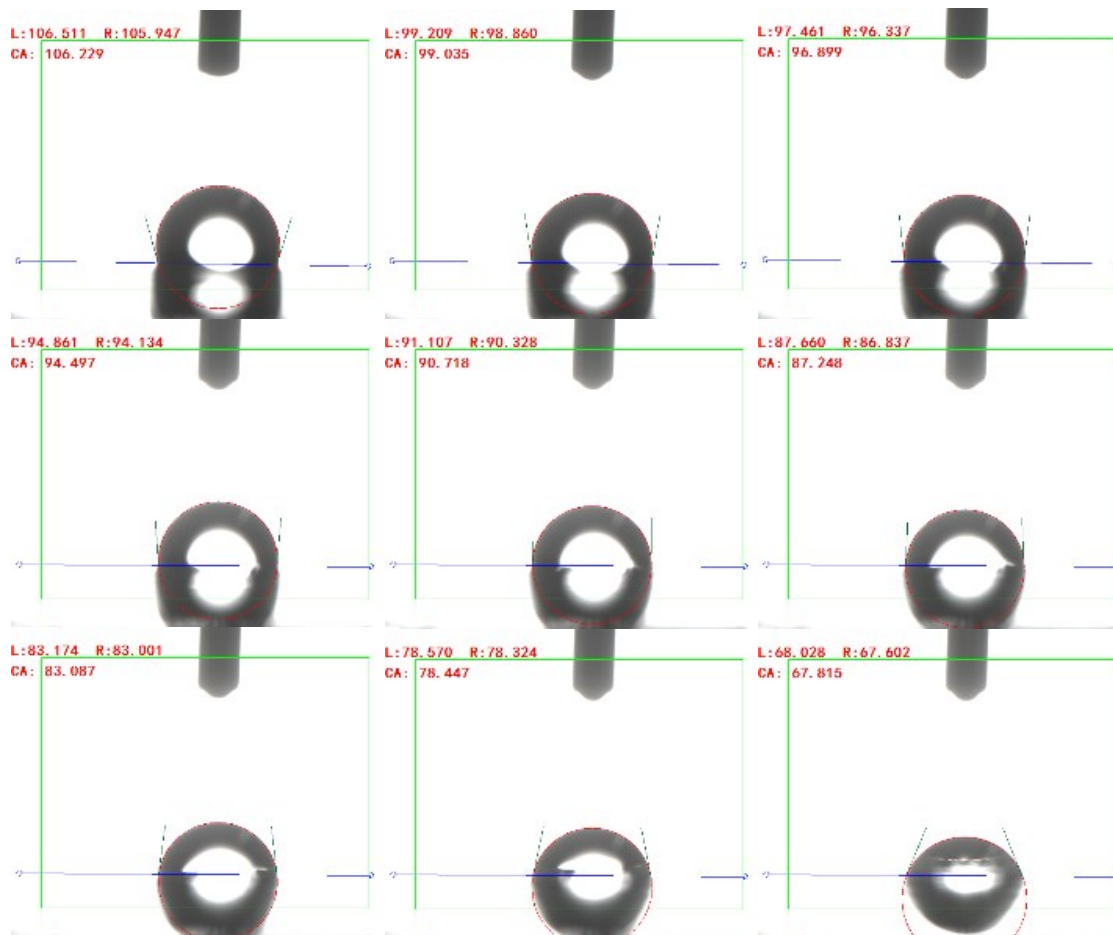


Figure S4. The change process of the contact angle of ceramic interdigital electrode.

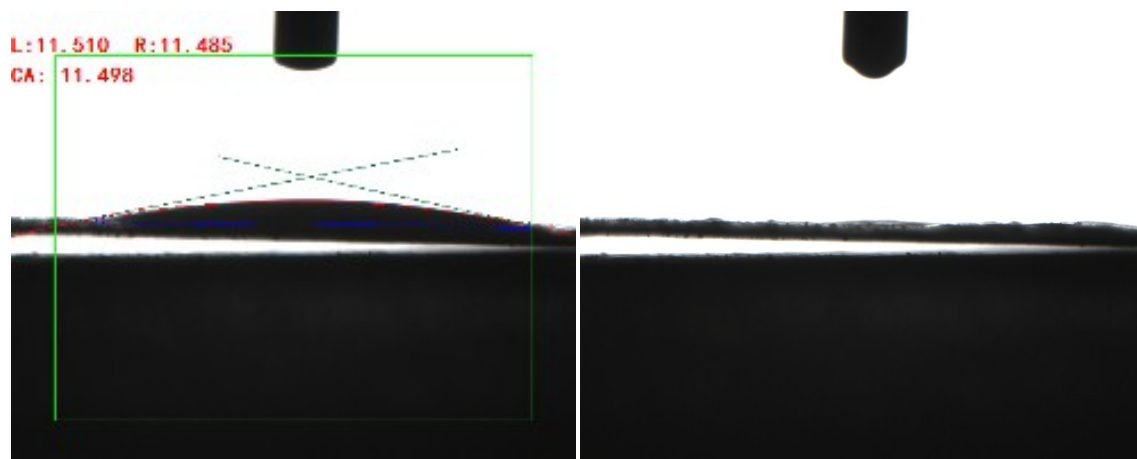


Figure S5. The change process of the contact angle of TaS₂ nanosheets humidity sensor based on PET with 50% sample adhesion rate.

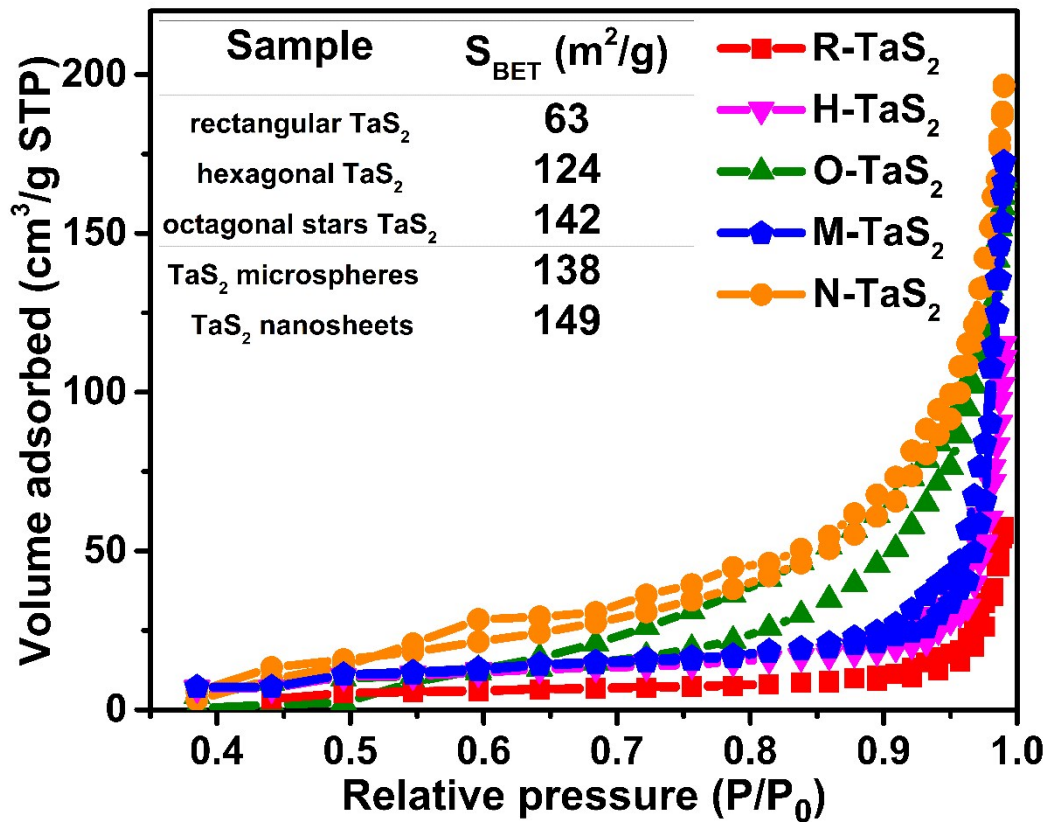


Figure S6. N_2 adsorption–desorption isotherms of R- TaS_2 (rectangular TaS_2), H- TaS_2 (hexagonal TaS_2), O- TaS_2 (octagonal stars TaS_2), M- TaS_2 (TaS_2 microspheres), and N- TaS_2 (TaS_2 nanosheets).

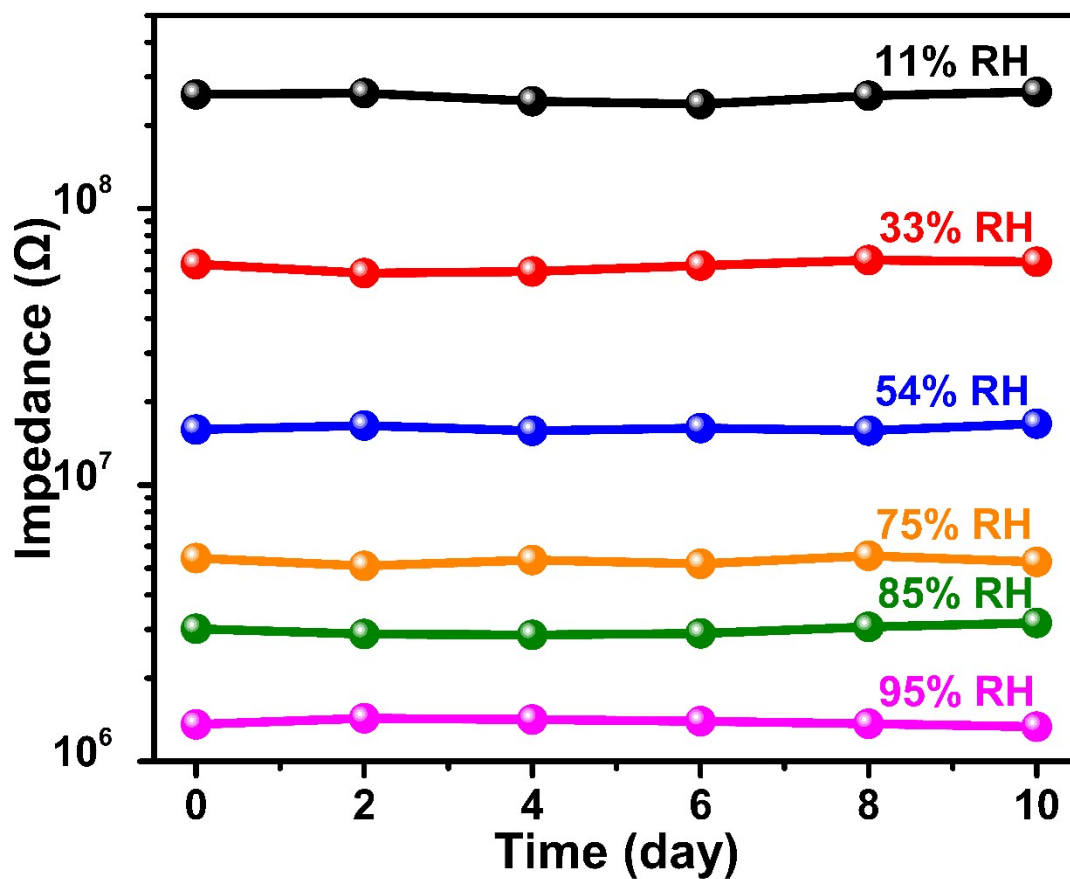


Figure S7. The response of TaS₂ nanosheets sensor monitored at different humidity conditions for 10 days.

Table S1. Comparison of TaS₂ based humidity sensor with other humidity sensors reported.

Material	RH range (%)	Order of impedance change	Sensitivity (%)	Hysteresis (%)	Response Time (s)	Recovery Time (s)	Reference
Black Phosphorus	11-97	3-4	507825 ($\Delta C/C$)	-	4.7	3	S1
MoS₂	0-35	2	10 ⁴	-	10	60	S2
VS₂	0-100	1	30 (R_{RH}/R_{dry})	-	40	50	S3
WS₂	11-97	1	469	-	12	13	S4
Graphene	50.0-70.6, 79.5-85.0	-	-0.224, -4.118 (dB/%RH)	-	4	23.7	S5
Graphene oxide	10-90	-	-	-	0.03	0.03	S6
TaS₂ nanosheets	11-95	2	201.9 ($\Delta R/R$)	0.02 (75% RH)	0.6	2	This work

References

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